NSN 5961-00-325-8649

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-325-8649 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **Overall Diameter:** 0.667 inches **End Application:** E-2c hawkeye aircraft. Velocity pool reparable piece parts. **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 working peak reverse voltage **Current Rating Per Characteristic:** 35.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Weapon system essential **Thread Series Designator: Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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